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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/626,418	07/23/2003	Tomohei Sugiyama	5000-5118	9860
27123 7590 06/20/2006			EXAMINER	
MORGAN & FINNEGAN, L.L.P.			MENZ, DOUGLAS M	
	INANCIAL CENTER , NY 10281-2101		ART UNIT	PAPER NUMBER
,,			2891	
			DATE MAILED: 06/20/2006	

Please find below and/or attached an Office communication concerning this application or proceeding.

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2	Application No.	Applicant(s)					
	10/626,418	SUGIYAMA ET AL.					
Office Action Summary	Examiner	Art Unit					
	Douglas M. Menz	2891					
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
Status							
1) Responsive to communication(s) filed on 01 Ju	ıne 2006.						
	<u> </u>						
3) Since this application is in condition for allowan	3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.					
Disposition of Claims							
4) Claim(s) 1-16 is/are pending in the application. 4a) Of the above claim(s) 1-10,13 and 14 is/are withdrawn from consideration. 5) Claim(s) 15 and 16 is/are allowed. 6) Claim(s) 11 and 12 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement.							
Application Papers							
9)☐ The specification is objected to by the Examiner 10)☒ The drawing(s) filed on 21 December 2005 is/ar Applicant may not request that any objection to the o Replacement drawing sheet(s) including the correcti 11)☐ The oath or declaration is objected to by the Examiner	re: a)⊠ accepted or b)⊡ objecdrawing(s) be held in abeyance. Se fon is required if the drawing(s) is ob	e 37 CFR 1.85(a). ojected to. See 37 CFR 1.121(d).					
Priority under 35 U.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 							
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date U.S. Patent and Trademark Office PTOL-326 (Rev. 7-05) Office Act	6) Other:						

DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 11-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Girrens et al. (US 6154364) in view of Jackson et al. (US 5006417) and Kawai et al. (US 6569524).

Regarding claim 11, Girrens discloses a semiconductor device comprising:

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A circuit board (Fig. 2);

A heat spreader (14, Figs. 1-2) which is formed of a low expansion material and is joined to the top face of the circuit board (Fig. 2 and Col. 3, lines: 9-30); and

A semiconductor element (12, Figs. 1-2) mounted onto the heat spreader (14, Figs. 1-2 and Col. 3, lines: 9-20).

Girrens further discloses that the heat spreader (14) can be made of various materials, wherein INVAR is preferred (Col. 3, lines: 24-30). Girrens does not disclose wherein the heat spreader comprises two or more kinds of SiC particles having different mean grain sizes and an Al material.

Jackson discloses a ternary metal matrix composite comprising SiC particles and an Al material (ABSTRACT and Col. 2, lines: 30-45). Jackson discloses that such a composite is suitable for electronic substrates, chip submounts, **heat sinks** and microcircuit subpackages among others (Col. 1, lines: 49-56). Jackson further discloses that the composite is advantageously used in place of INVAR because INVAR is a poor thermal conductor (Col. 2, lines: 5-8), wherein Jackson's composite is a good thermal conductor (Col. 24-31). Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to use Jackson's composite instead of INVAR for Girren's heat spreader since Jackson explicitly discloses the advantages of using the composite over INVAR, i.e. better heat conductivity. Furthermore, Jackson discloses that the coefficient of thermal expansion of the composite can be tailored to meet specific needs (Col. 2, lines: 26-30), which is an additional advantage.

Jackson does not explicitly disclose the grain size specifics of the SiC particles. Kawai discloses a heat spreader composition which incorporates two or more kinds of SiC particles having different mean grain sizes (i.e. 200 – 500um, Col. 28). Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to use SiC particles having different mean grain sizes as taught by Kawai.

Regarding claim 12, Girrens further discloses wherein the circuit board is composed of a metal substrate (10, Fig. 2 and Col. 3, lines: 14-16) with an insulating layer and a wiring layer formed on its surface in order (Fig. 2, *The examiner interprets the lines and squares on the circuit board to be symbolic of wires and associated bond pads that cover the top of the substrate 10, respectively. Given that the substrate 10 is stainless steel (Col. 3, lines: 14-16) it would be inherent that an insulating layer separate the wiring layer from the metal substrate, otherwise it would be rendered inoperable.);*

Girrens further discloses wherein the heat spreader (14, Figs. 1-2) being joined to the top face of the wiring layer through solder (Col. 3, lines: 15-20),

And the semiconductor element (12, Figs. 1-2) being joined to the top face of the heat spreader (14, Figs. 1-2) through solder (Col. 3, lines: 15-20).

Allowable Subject Matter

Claims 15-16 are allowed.

The following is a statement of reasons for the indication of allowable subject matter:

There is no teaching or suggestion in the art of record disclosing a semiconductor device comprising a heat spreader configured in accordance with claim 15 wherein the two or more kinds of SiC particles having different mean grain sizes comprise SiC particles with a mean grain size of 100 microns and SiC particles with a mean grain size of 8 microns. Therefore, independent claim 15 is deemed allowable along with its dependent claim 16.

Response to Arguments

Applicant's arguments with respect to claims 11-12 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Douglas M. Menz whose telephone number is 571-272-1877. The examiner can normally be reached on M-F 8-5.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Bill Baumeister can be reached on 571-272-1722. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

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